NSN 5961-01-388-0021

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-388-0021 **Inclosure Material:** Ceramic **Overall Length:** 1.225 inches **Function For Which Designed:** Switching **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, dc **Power Rating Per Characteristic:** 3.0 kilowatts small-signal input power, common-collector preset **Capacitance Rating In Picofarads:** 3.0 **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Test Features:** Screened to 580-0629-002 **Test Data Document:** 13499-922-6120 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: